

2MBI300VH-120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 300A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines



Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
	Collector-Emitter voltage	Vces			1200	V	
Inverter	Gate-Emitter voltage	V _{GES}			±20	V	
	Collector current	Ic	Continuous	Tc=100°C	300		
				Tc=25°C	360		
		Ic pulse	1ms		600	А	
		-lc			300		
		-lc pulse	1ms		600		
	Collector power dissipation	Pc	1 device		1600	W	
Junction temperature		Tj			175		
Operating junction temperature (under switching conditions)		Tjop			150	°C	
Case temperature		Tc			125		
Storage temperature		Tstg			-40 ~ +125		
Isc	plation voltage between terminal and copper base (*1)	Viso	AC : 1min.		2500	VAC	
Screw torque Mounting (*2)					6.0	N m	
30	Terminals (*3)	-			5.0	IN III	

Note *1: All terminals should be connected together during the test. Note *2: Recommendable Value : 3.0-6.0 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-5.0 Nm (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

ems	Cumbala	Conditions		Characteristics			Heite
eilis	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	2.0	mA
Gate-Emitter leakage current	Iges	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	400	nA
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 300mA	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	V		Tj=25°C	-	1.95	2.40	V
	V _{CE (sat)} (terminal)	V _{GE} = 15V I _C = 300A	Tj=125°C	-	2.25	-	
	(terrillial)		Tj=150°C	-	2.30	-	
	V		Tj=25°C	-	1.75	2.15	
	V _{CE (sat)}		Tj=125°C	-	2.05	-	
	(chip)		Tj=150°C	-	2.10	-	
Input capacitance	Cies	$V_{CE} = 10V$, $V_{GE} = 0V$, $f = 1MHz$		-	24	-	nF
Turn-on time	ton	Vcc = 600V Ls = 30nH Ic = 300A		-	0.60	-	μs
	tr			-	0.20	-	
	tr (i)	V _{GE} = ±15V	-	0.05	-		
Turn-off time	toff	R _G = 1.8Ω Tj = 150°C		-	0.80	-	
	tf			-	0.08	-	
Forward on voltage	V _F	V _{GE} = 0V	Tj=25°C	-	1.90	2.40	V
			Tj=125°C	-	2.05	-	
	(terminal)		Tj=150°C	-	2.00	-	
	VF	I _F = 300A	Tj=25°C	-	1.70	2.15	
			Tj=125°C	-	1.85	-	
	(chip)		Tj=150°C	-	1.80	-	
Reverse recovery time	trr	I _F = 300A		-	0.15	-	μs

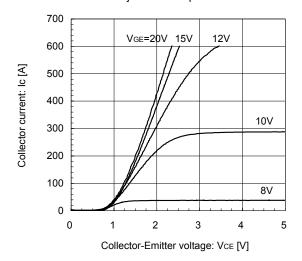
Thermal resistance characteristics

Items	Symbols	Conditions	Ch	Characteristics				
itellis	Symbols		min.	typ.	max.	Units		
Thermal registeres (4device)	Rth(j-c)	Inverter IGBT	-	-	0.093	°C/W		
Thermal resistance (1device)	Kill(j-c)	Inverter FWD	-	-	0.150			
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	_	0.0125	_]		

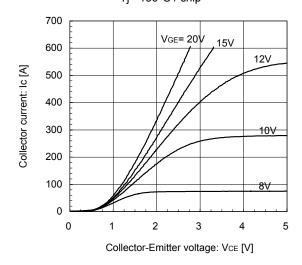
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

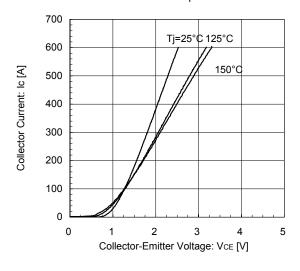
Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip



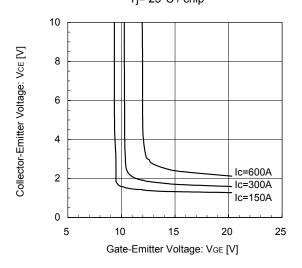
Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



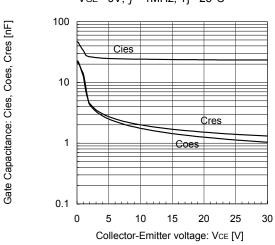
Collector current vs. Collector-Emitter voltage (typ.) VGE= 15V / chip



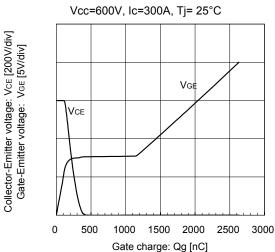
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25°C / chip



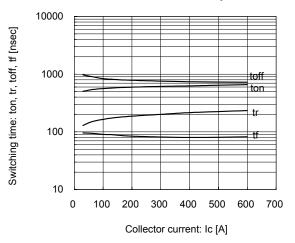
Gate Capacitance vs. Collector-Emitter Voltage (typ.) VGE= 0V, f= 1MHz, Tj= 25°C



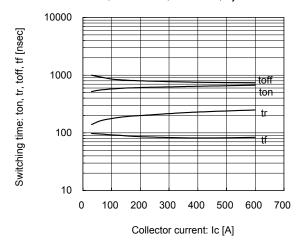
Dynamic Gate Charge (typ.)



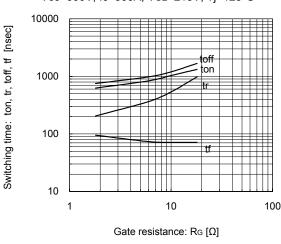
Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.8 Ω , Tj=125°C



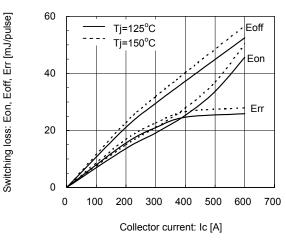
Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.8 Ω , Tj=150°C



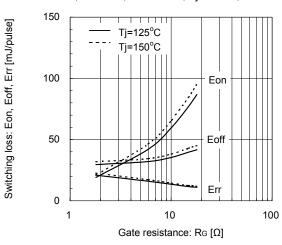
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=300A, VgE=±15V, Tj=125°C



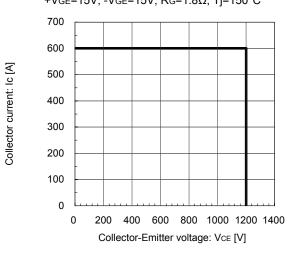
Switching loss vs. Collector current (typ.) Vcc=600V, VgE=±15V, Rg=1.8Ω, Tj=125°C, 150°C

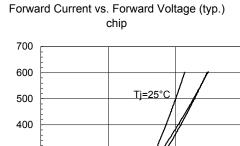


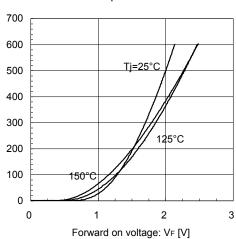
Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=300A, VgE=±15V, Tj=125°C, 150°C



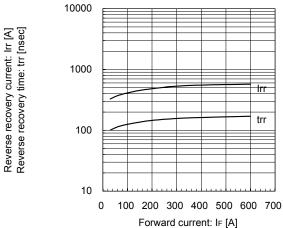
Reverse bias safe operating area (max.) +VgE=15V, -VgE=15V, Rg=1.8 Ω , Tj=150°C



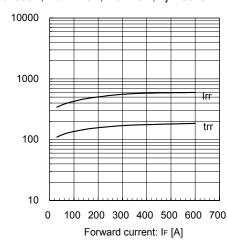




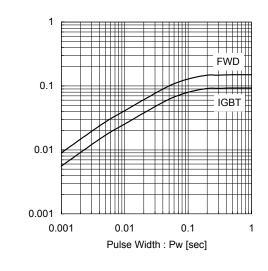
Reverse Recovery Characteristics (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.8 Ω , Tj=125 $^{\circ}$ C



Reverse Recovery Characteristics (typ.) Vcc=600V, VgE=±15V, Rg=1.8Ω, Tj=150°C



Transient Thermal Resistance (max.)

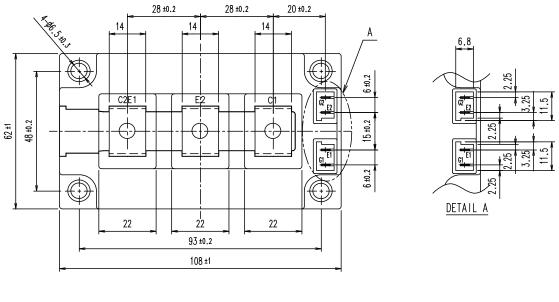


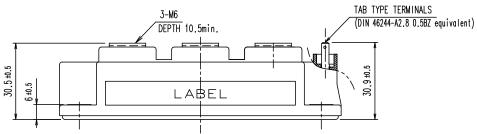
Forward current: IF [A]

Thermal resistanse: Rth(j-c) [°C/W]

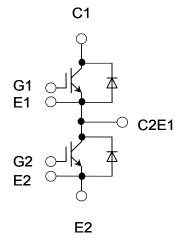
http://www.fujielectric.com/products/semiconductor/

■ Outline Drawings, mm





■ Equivalent Circuit Schematic



http://www.fujielectric.com/products/semiconductor/

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- Communications equipment (terminal devices)
- · Measurement equipment

- · Machine tools
- Audiovisual equipment
- Electrical home appliances
- Personal equipment Industrial robots etc.
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- Emergency equipment for responding to disasters and anti-burglary devices · Medical equipment
- · Safety devices

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- Aeronautic equipment
- · Nuclear control equipment

Trunk communications equipment

· Gas leakage detectors with an auto-shut-off feature

- Submarine repeater equipment
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